

## DATA SHEET

## **DEVICE NUMBER: BWL-10C1G02-S**

SHEET	1	2	3	4	5	6	7			CONTENTS
2010.01.13	1.0	1.0	1.0	1.0	1.0	1.0	-			Preliminary
2010.04.19	1.1	1.1	1.1	1.1	1.1	1.1	-			P3
2010.05.14	1.2	1.2	1.2	1.2	1.2	1.2	1.2			Add P5
2010.07.23	1.3	1.3	1.3	1.3	1.3	1.3	1.3		V A	Modified storage and velding conditions. Amendments to the content Welding.

## 佰鴻工業股份有限公司

BRIGHT LED ELECTRONICS CORP.

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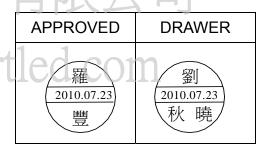
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BWL-10C1G02-S

#### Features:

1. Input power: 1W.

2. Chip material: AllnGaN.

3. Emitted color: Green.

4. High lumen output.

5. High flux density.

6. Low power consumption.

7. Efficient heat transfer.

8. Exterior lens is silicon.

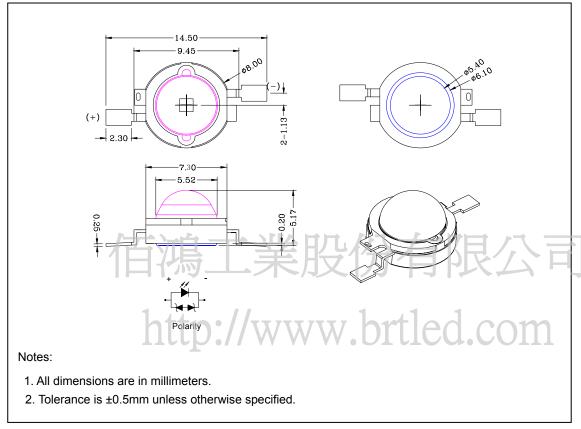
9. Add extra heat sink is necessary.

\* Must increasing heatsink, let the unit temperature below 60  $^{\circ}$ C.

## Applications:

- 1. Torch.
- 2. Head Light.
- 3. Architectural Lighting.
- 4. LCD Backlight.

## Package dimensions :





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## ■ Absolute maximum ratings (T<sub>J</sub>=25°C)

Parameter	Symbol	Rating	Unit	
Power Dissipation	$P_{D}$	1.0	W	
DC Forward Current*1	I <sub>F</sub>	350	mA	
Peak Pulsed Forward Current*2	I <sub>FP</sub>	1.0	А	
LED Junction Temperature	TJ	130	°C	
Operating Temperature	Topr	-40~ +85	°C	
Storage Temperature	Tstg	-40~ +100	°C	
Reverse Voltage	$V_R$	5	V	
Manual Soldering (T=5 sec)	Tsol	300 ± 5	°C	

<sup>\*1</sup>Proper current derating must be followed to keep LED junction temperature (T<sub>J</sub>) below the maximum.

## ■ Electrical & Optical Characteristics (T<sub>J</sub>=25°C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =350mA	-	3.3	3.8	V
Total Flux	Ф	I <sub>F</sub> =350mA	55	60	-	lm
Peak Wavelength	λр	I <sub>F</sub> =350mA	-	525	-	nm
Dominant Wavelength	λd	I <sub>F</sub> =350mA	520	-	530	nm
Spectral Line Half-width		I <sub>F</sub> =350mA	臣方	35	-	nm
Reverse Current	R	V <sub>R</sub> =5V		Z H	10	μΑ
Thermal Resistance, Junction To Case	$R\theta_{J-C}$	I <sub>F</sub> =350mA	-	9	-	°C/W
Viewing Angle	2θ <sub>1/2</sub>	I <sub>F</sub> =350mA	. 00	120	-	degree

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 $<sup>^{\</sup>star 2}$ Condition for I<sub>FP</sub> is pulsed with 1/10 duty and 0.1msec width.



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#### Typical electro-optical characteristics curves

Fig.1 RELATIVE INTENSITY VS. WAVELENGTH

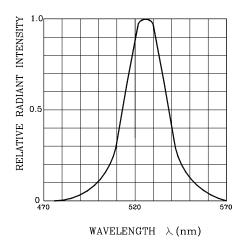


Fig.3 FORWARD CURRENT VS. FORWARD VOLTAGE

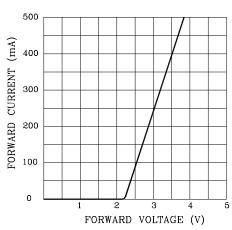


Fig.2 FORWARD CURRENT VS. AMBIENT TEMPERATURE

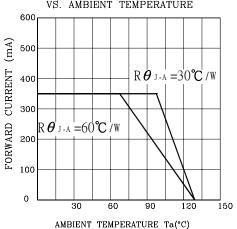


Fig.4 RELATIVE LUMINOUS INTENSITY VS. JUNCTION TEMPERATURE

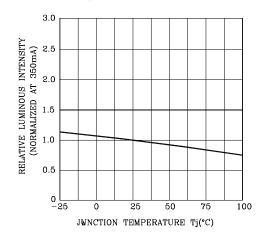


Fig.5 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT 2.0 (at Tj=25°C)

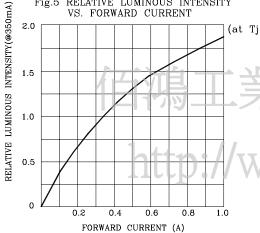
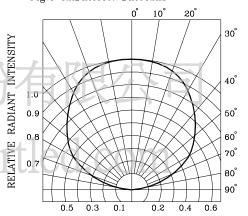


Fig.6 RADIATION DIAGRAM





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## ● Total Flux Bin Limits (At 350mA)

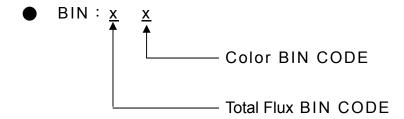
BIN CODE	Min. (lm)	Max. (lm)
N	55	72
Р	72	93

Tolerance for each Bin limit is ± 15 %

#### Color Bin Limits(At 350mA)

BIN CODE	Min. (nm)	Max. (nm)
6	520	525
7	525	530

Tolerance for each bin limit is ± 1 nm



Notes:

1. Bin categories are established for classification of products. Products may not be available in all bin categories.

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#### Soldering :

1. Manual Soldering

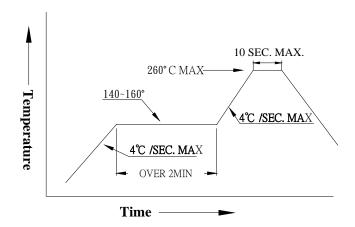
The temperature of the iron tip should not be higher than 300°C and Soldering time to be within 3 seconds per solder-pad.

2. Reflow Soldering

Preheating: 140°C ~160°C ±5°C, within 2 minutes.

Operation heating: 260°C (Max.) within 10 seconds.(Max)

Gradual Cooling (Avoid quenching).



## Handling:

Care must be taken not to damage LED's silicone while exposing to high temperature or contact LED's silicone with hard or sharp objects, such as metal hook, tweezer or sand blasting.

### Notes for designing:

Current limiting resistor or a constant current power supply must be used in the circuit to drive BRIGHT LEDs within the rated figures and not to overload BRIGHT LEDs with instantaneous voltage at the turning ON and OFF cycles.

When using pulse driving, the average current must be within the rated figures. And the circuit should be designed to avoid reverse voltage when turning off the BRIGHT LEDs.





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### Storage:

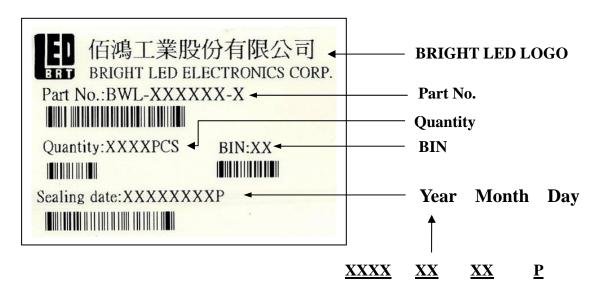
In order to avoid the absorption of moisture, it is recommended to solder BRIGHT LEDs as soon as possible after unpacking the sealed envelope.

If the envelope is still packed, to store it in the environment as following:

- (1) Temperature :  $5^{\circ}$ C  $30^{\circ}$ C ( $41^{\circ}$ F) Humidity : RH 60% Max.
- (2) After this bag is opened, devices that will be applied to infrared reflow, vapor-phase reflow, or equivalent soldering process must be:
- a. Completed within 168 hours.
- b. Stored at less than 30% RH.
- (3) Devices require baking before mounting, if:
  - (2) a or (2) b is not met.
- (4) If baking is required, devices must be baked under below conditions: 48 hours at  $60^{\circ}\text{C}\pm3^{\circ}\text{C}$ .

#### Package and Label of Products:

- (1) Package: Products are packed in one bag of 1000 pcs (one taping reel) and a label is attached to each bag.
- (2) Label:



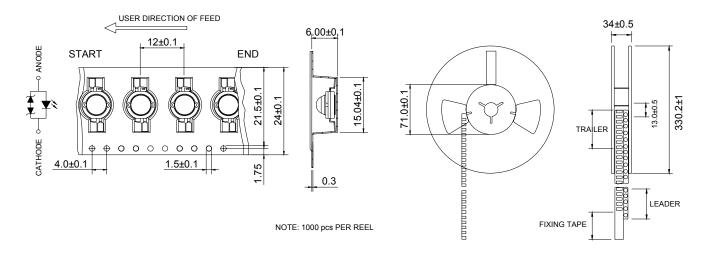
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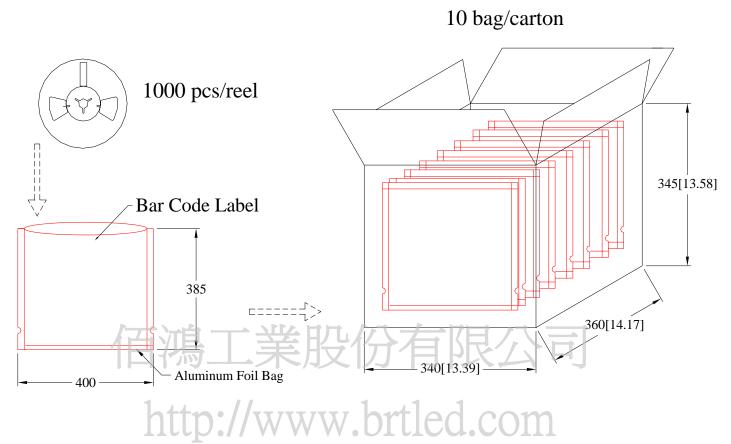


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#### Tapping and packaging specifications(Units: mm)



#### Package Method : (unit:mm)



NOTES: Bag: Tolerance is ± 5 mm unless otherwise noted.

Carton: Tolerance is ± 10 mm unless otherwise noted.